

SEP 11 2006

Atty. Dkt. No. 039153-0649 (H0982)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Xiang et al.
Title: FULLY DEPLETED STRAINED
SEMICONDUCTOR ON
INSULATOR TRANSISTOR
AND METHOD OF MAKING
THE SAME
Appl. No.: 10/773,026
Filing Date: 02/05/2004
Examiner: Doty, Heather Anne
Art Unit: 2813
Conf. No.: 6093

CERTIFICATE OF FACSIMILE TRANSMISSION I hereby certify that this paper is being facsimile transmitted to the United States Patent and Trademark Office, Alexandria, Virginia on the date below. Carolyn Simpson (Printed Name) <i>Carolyn Simpson</i> (Signature) September 11, 2006 (Date of Deposit)
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AMENDMENT AND REPLY UNDER 37 CFR 1.111

Mail Stop AMENDMENT
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This communication is responsive to the Non-Final Office Action dated May 11, 2006,
concerning the above-referenced patent application.

Amendments to the Claims are reflected in the listing of claims which begins on page 2
of this document.

Remarks/Arguments begin on page 6 of this document.

Please amend the application as follows: